HALOGEN FREE



### Vishay General Semiconductor

# **Dual High-Voltage Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.50 \text{ V}$  at  $I_F = 5 \text{ A}$ 



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 30 A			
$V_{RRM}$	170 V			
I <sub>FSM</sub>	210 A			
$V_F$ at $I_F = 30 A$	0.72 V			
T <sub>J</sub> max.	175 °C			
Package	TO-220AB			
Diode variation	Dual common cathode			

#### **FEATURES**

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses

High efficiency operation

Solder dip 275 °C max. 10 s, per JESD 22-B106

 Material categorization: For definitions of compliance please see <a href="https://www.vishav.com/doc?99912">www.vishav.com/doc?99912</a>

#### TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

#### **MECHANICAL DATA**

Case: TO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and

commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	V60170G	UNIT	
Maximum repetitive peak reverse voltage		$V_{RRM}$	170	V	
Maximum average forward rectified current (fig. 1)	per device	I <sub>F(AV)</sub>	60	Δ.	
	per diode		30	A	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I <sub>FSM</sub>	210	А	
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000	V/µs	
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-40 to +175	°C	



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I <sub>F</sub> = 5 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.65	-	V	
	I <sub>F</sub> = 15 A			0.78	-		
	I <sub>F</sub> = 30 A			0.87	1.02		
	I <sub>F</sub> = 5 A	T <sub>A</sub> = 125 °C		0.50	-		
	I <sub>F</sub> = 15 A			0.62	-		
	I <sub>F</sub> = 30 A			0.72	0.80		
Reverse current per diode	V <sub>R</sub> = 136 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	1.5	-	μΑ	
		T <sub>A</sub> = 125 °C		2.5	-	mA	
	V <sub>R</sub> = 170 V	T <sub>A</sub> = 25 °C		-	450	μΑ	
		T <sub>A</sub> = 125 °C		5	50	mA	

#### **Notes**

<sup>(2)</sup> Pulse test: Pulse width  $\leq$  20 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	V60170G	UNIT	
Typical thermal resistance	per diode	$R_{ hetaJC}$	1.0	°C/W	
	per device		0.7		

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	V60170G-M3/4W	1.89	4W	50/tube	Tube		

### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

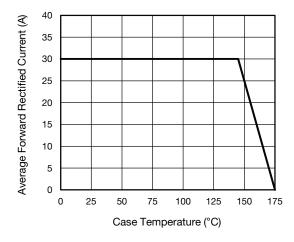


Fig. 1 - Maximum Forward Current Derating Curve

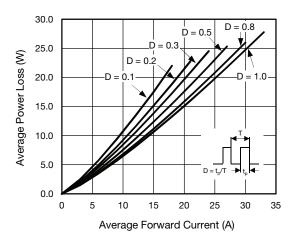


Fig. 2 - Forward Power Loss Characteristics Per Diode

<sup>(1)</sup> Pulse test: 300 µs pulse width, 1 % duty cycle



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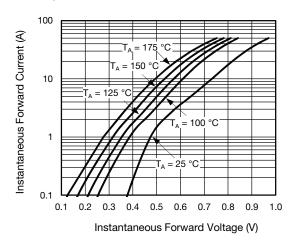


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

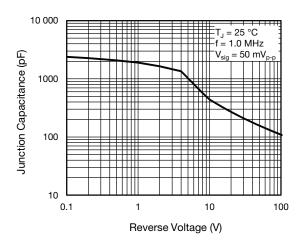


Fig. 5 - Typical Junction Capacitance Per Diode

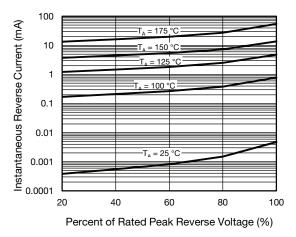


Fig. 4 - Typical Reverse Characteristics Per Diode

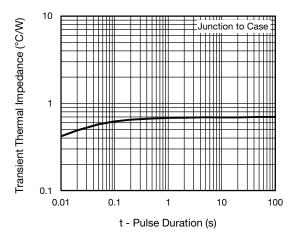
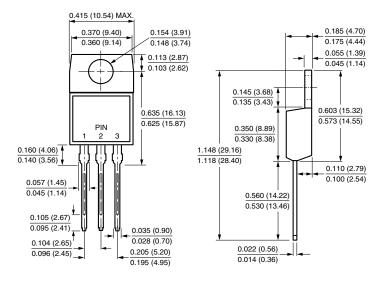


Fig. 6 - Typical Transient Thermal Impedance Per Device

#### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

#### TO-220AB





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V60170G-M3/4W